



SEMITOP® 3

IGBT Module

SK20GD066ET

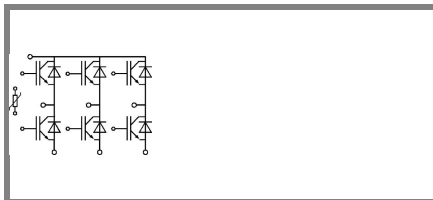
Target Data

Features

- Compact design
- One screw mounting
- Heat transfer and isolation through direct copper bonded aluminium oxide ceramic (DCB)
- Trench IGBT technology
- CAL technology FWD
- Integrated NTC temperature sensor

Typical Applications*

- Inverter up to 6,3 kVA
- Typ. motor power 4 kW



GD-ET

Absolute Maximum Ratings		$T_s = 25\text{ °C}$, unless otherwise specified		
Symbol	Conditions	Values		Units
IGBT				
V_{CES}	$T_j = 25\text{ °C}$	600		V
I_C	$T_j = 175\text{ °C}$	$T_s = 25\text{ °C}$	30	A
		$T_s = 70\text{ °C}$	25	A
I_{CRM}	$I_{CRM} = 2 \times I_{Cnom}$	40		A
V_{GES}		± 20		V
t_{psc}	$V_{CC} = 360\text{ V}$; $V_{GE} \leq 20\text{ V}$; $T_j = 150\text{ °C}$ $V_{CES} < 600\text{ V}$	6		µs
Inverse Diode				
I_F	$T_j = 175\text{ °C}$	$T_s = 25\text{ °C}$	31	A
		$T_s = 70\text{ °C}$	24	A
I_{FRM}	$I_{FRM} = 2 \times I_{Fnom}$	40		A
I_{FSM}	$t_p = 10\text{ ms}$; half sine wave $T_j = 150\text{ °C}$	95		A
Module				
$I_{t(RMS)}$				A
T_{vj}		-40 ... +175		°C
T_{stg}		-40 ... +125		°C
V_{isol}	AC, 1 min.	2500		V

Characteristics		$T_s = 25\text{ °C}$, unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
IGBT					
$V_{GE(th)}$	$V_{GE} = V_{CE}$, $I_C = 0,29\text{ mA}$	5	5,8	6,5	V
I_{CES}	$V_{GE} = 0\text{ V}$, $V_{CE} = V_{CES}$	$T_j = 25\text{ °C}$	0,0011		mA
		$T_j = 125\text{ °C}$			mA
I_{GES}	$V_{CE} = 0\text{ V}$, $V_{GE} = 20\text{ V}$	$T_j = 25\text{ °C}$	300		nA
		$T_j = 125\text{ °C}$			nA
V_{CE0}		$T_j = 25\text{ °C}$	0,9	1,1	V
		$T_j = 150\text{ °C}$	0,8	1	V
r_{CE}	$V_{GE} = 15\text{ V}$	$T_j = 25\text{ °C}$	27,5	37,5	mΩ
		$T_j = 150\text{ °C}$	42,5	52,5	mΩ
$V_{CE(sat)}$	$I_{Cnom} = 20\text{ A}$, $V_{GE} = 15\text{ V}$	$T_j = 25\text{ °C}_{chiplev.}$	1,45	1,85	V
		$T_j = 125\text{ °C}_{chiplev.}$	1,65	2,05	V
C_{ies}	$V_{CE} = 25$, $V_{GE} = 0\text{ V}$	$f = 1\text{ MHz}$	1,1		nF
C_{oes}			0,071		nF
C_{res}			0,032		nF
Q_G	$V_{GE} = -7V...+15V$	225		nC	
$t_{d(on)}$	$R_{Gon} = 15\text{ }\Omega$ $di/dt = 3300\text{ A}/\mu\text{s}$	$V_{CC} = 300V$ $I_C = 20A$	16		ns
t_r			15		ns
E_{on}			0,34		mJ
$t_{d(off)}$	$R_{Goff} = 15\text{ }\Omega$ $di/dt = 3300\text{ A}/\mu\text{s}$	$T_j = 150\text{ °C}$ $V_{GE} = \pm 15V$	166		ns
t_f			40		ns
E_{off}			0,63		mJ
$R_{th(j-s)}$	per IGBT	1,95		K/W	

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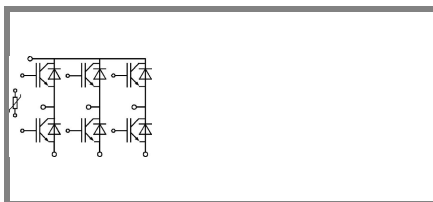
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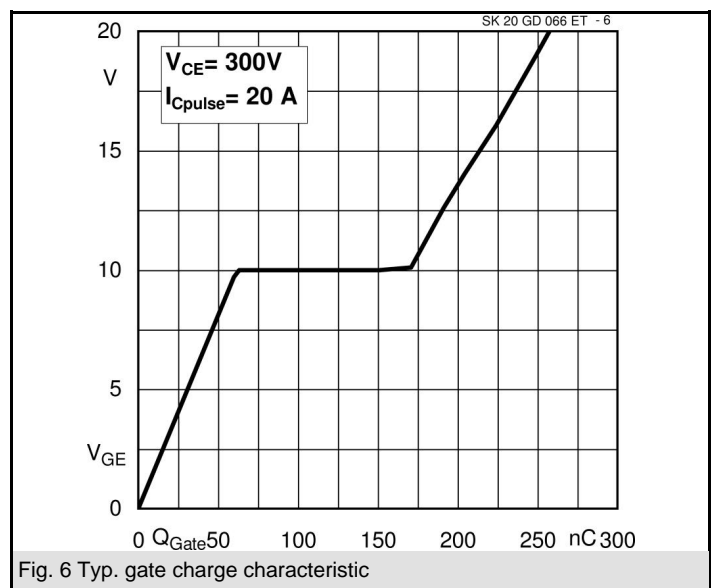
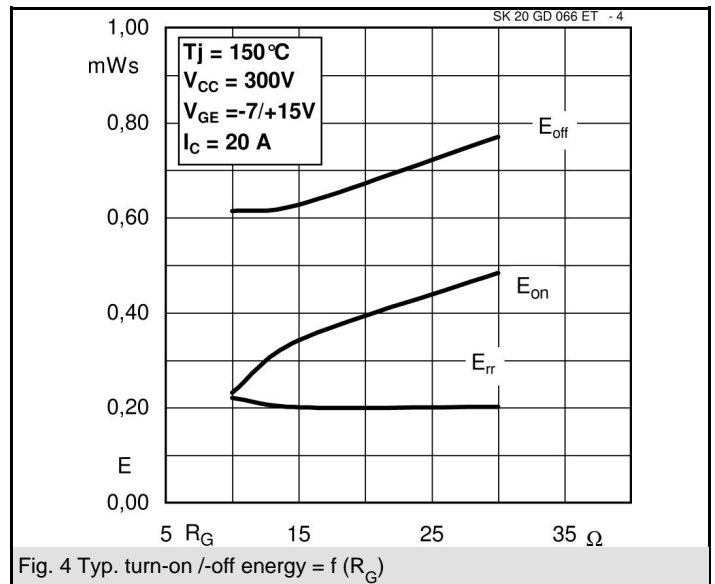
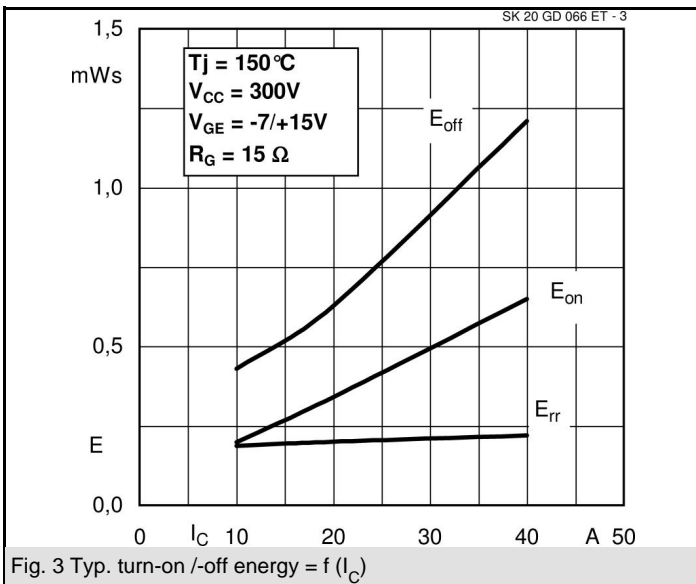
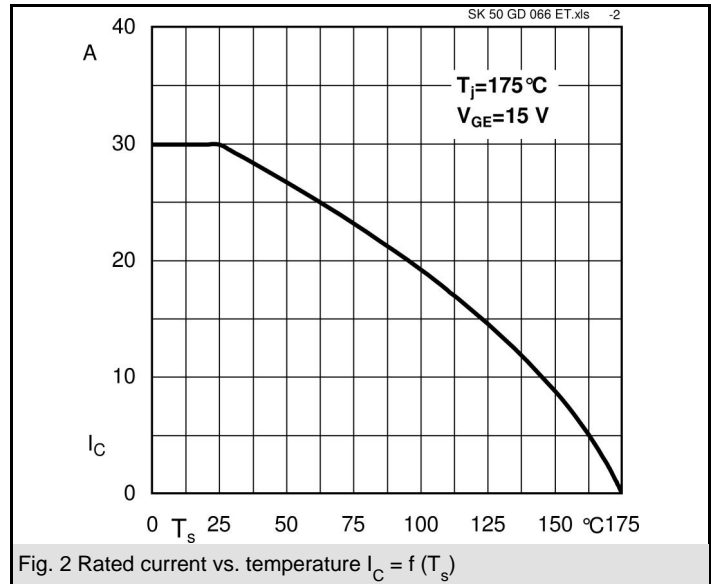
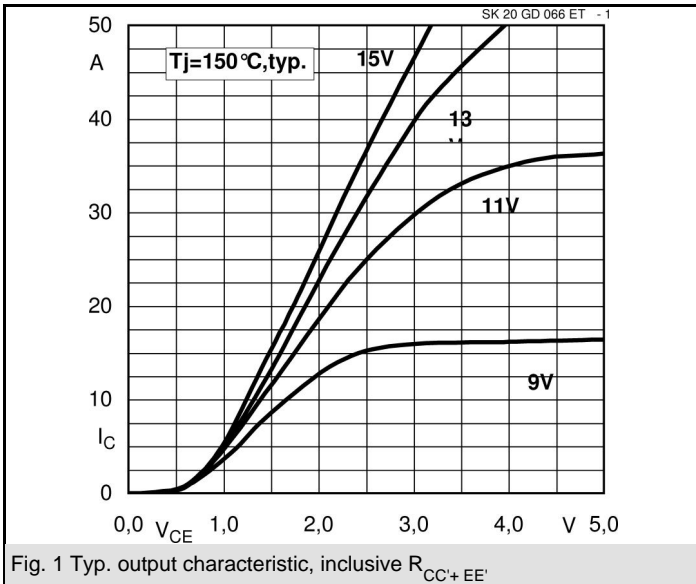


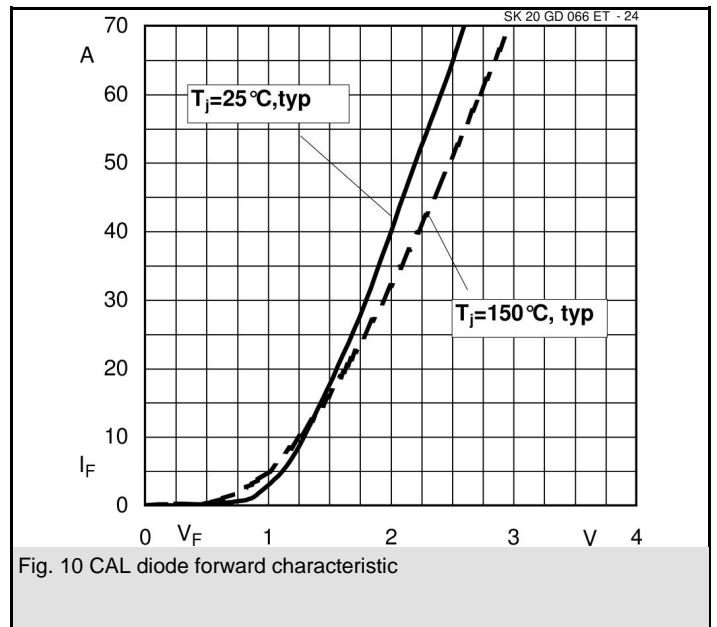
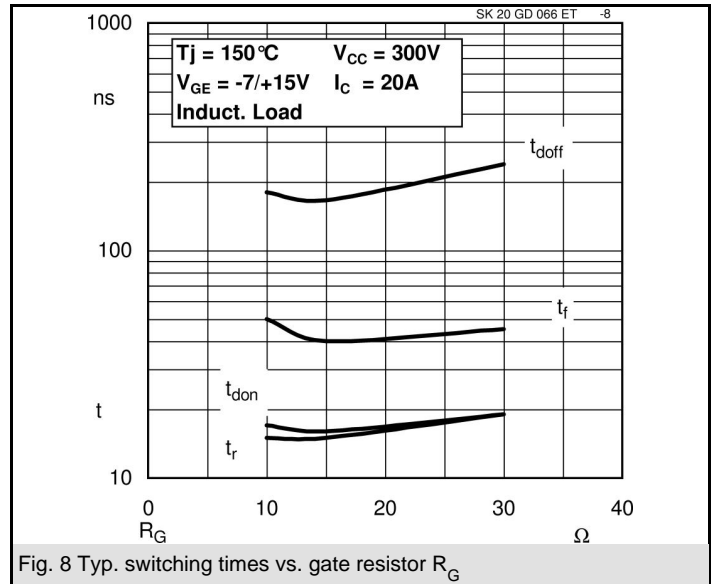
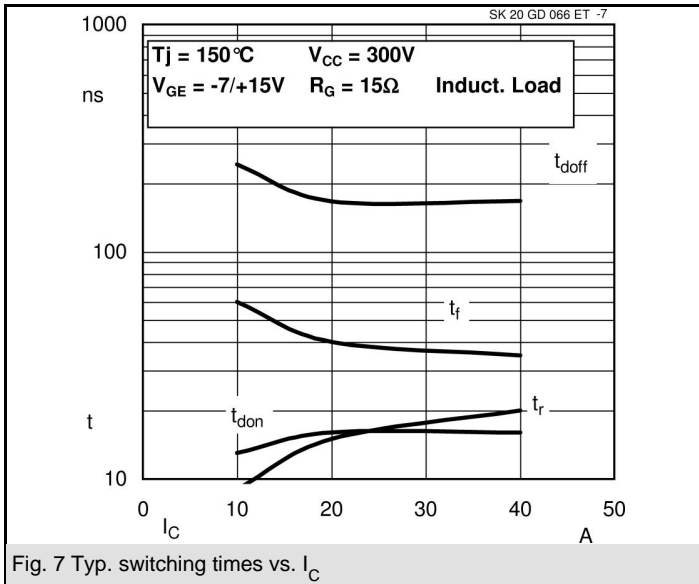
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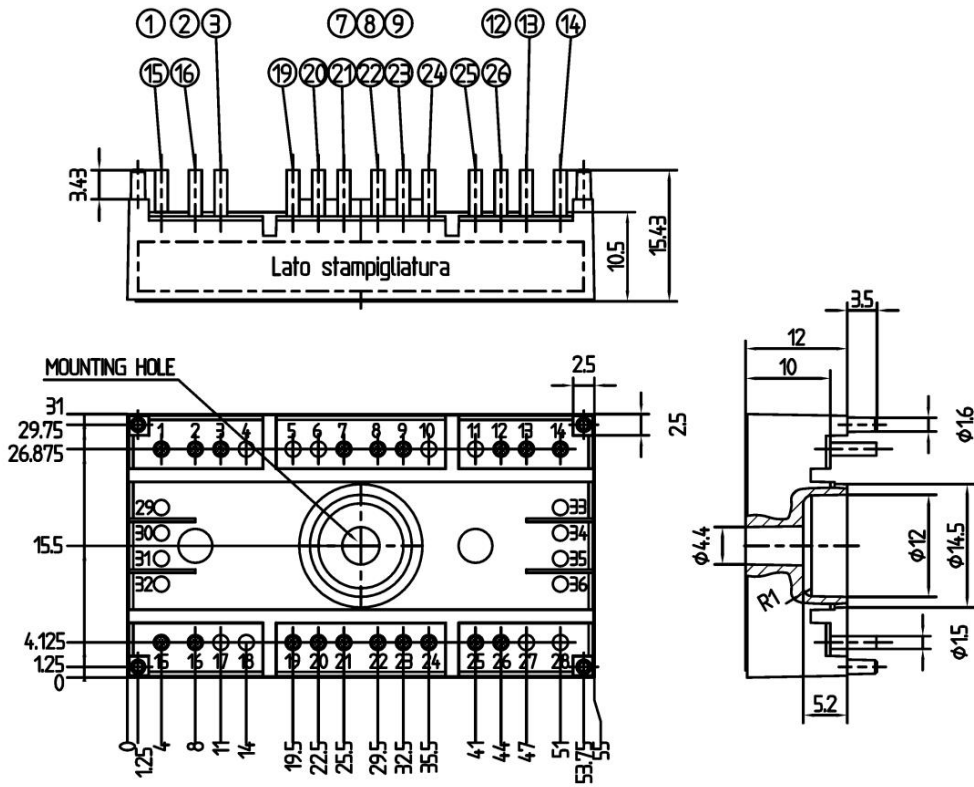
Characteristics		min.	typ.	max.	Units
Inverse Diode					
$V_F = V_{EC}$	$I_{Fnom} = 20 \text{ A}; V_{GE} = 0 \text{ V}$		1,45	1,7	V
	$T_j = 25 \text{ }^\circ\text{C}_{chiplev.}$				
	$T_j = 150 \text{ }^\circ\text{C}_{chiplev.}$		1,45	1,7	V
V_{F0}			1	1,1	V
	$T_j = 25 \text{ }^\circ\text{C}$				
	$T_j = 150 \text{ }^\circ\text{C}$		0,9	1	V
r_F			22,5	30	mΩ
	$T_j = 25 \text{ }^\circ\text{C}$				
	$T_j = 150 \text{ }^\circ\text{C}$		27,5	35	mΩ
I_{RRM}	$I_F = 30 \text{ A}$		32		A
Q_{rr}	$di/dt = 3300 \text{ A}/\mu\text{s}$		2		μC
E_{rr}	$V_{CC} = 300\text{V}$		0,2		mJ
$R_{th(j-s)D}$	per diode		2,46		K/W
M_s	to heat sink	2,25		2,5	Nm
w			30		g
Temperature sensor					
R_{100}	$T_s = 100^\circ\text{C} (R_{25} = 5\text{k}\Omega)$		493±5%		Ω

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

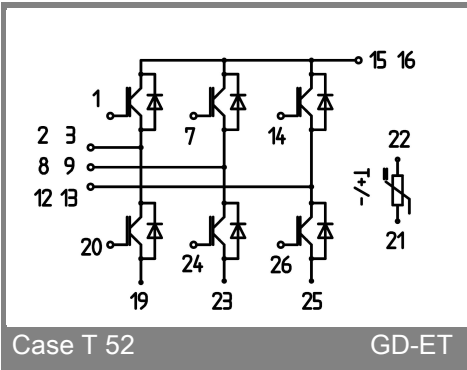
* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.







Case T52 (Suggested hole diameter, in the PCB, for solder pins and plastic mounting pins: 2mm)



Case T 52

GD-ET